

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

2822

Applicant: Leonard Forbes

Title: SILICON-GERMANIUM DEVICES FOR CMOS FORMED BY ION IMPLANTATION AND SOLID PHASE EPITAXIAL REGROWTH

Docket No.: 303.229US2

Filed: August 11, 1998

Examiner: Mark Prenty

Customer No.: 21186



Serial No.: 09/132157

Due Date: October 9, 2003

Group Art Unit: 2822

Confirmation No.: 8931

**MS Non-Fee Amendment**

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

We are transmitting herewith the following attached items (as indicated with an "X"):

- A return postcard.  
 An Amendment and Response (10 Pages).

If not provided for in a separate paper filed herewith, Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

Customer Number 21186

By: 

Atty: David C. Peterson

Reg. No. 47,857

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: MS Non-Fee Amendment, Commissioner for Patents, P.O.Box 1450, Alexandria, VA 22313-1450, on this 9 day of October, 2003.

Name

Tina Kohout

Signature

Z. H. J.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

Customer Number 21186

(GENERAL)

S/N 09/132157

PATENT

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OCT 14 2003  
SC130  
PATENT & TRADEMARK OFFICE  
Commissioner for Patents

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Alexandria, VA 22313-1450

AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Applicant has reviewed the Office Action mailed on July 9, 2003. Please amend the above-identified patent application as follows.

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